

RECTIFICATION FILTERING STABILIZATION

Introduction :

Most devices used in electronics require a DC power supply. One solution would be to use batteries or cells, but their lifespan is limited, and they cannot provide high supply currents. It is possible to obtain a DC power source from the AC mains voltage (Effective voltage = 220V, frequency = 50Hz). This power supply mainly consists of three parts (see Figure 1):

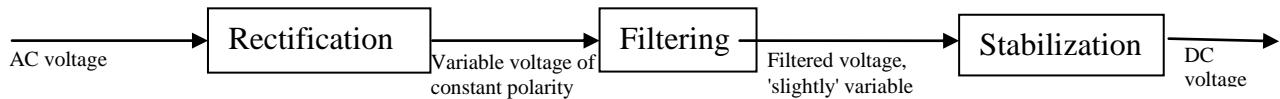


Figure1

The first stage ensures the rectification of the AC voltage using components such as diodes, allowing for a variable voltage but with the same polarity or sign. The second stage performs filtering, resulting in a nearly constant voltage with low ripple. The third stage stabilizes the obtained voltage to compensate for load variations, mains disturbances, and other fluctuations, ...

I- Static Characteristic of the Diode:

The diode is a non-linear component (see its characteristic in Figure 2). This very important property of the diode is widely used in electronics for applications such as rectification and detection, ...

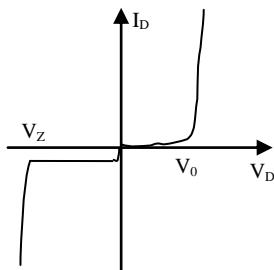


Figure2

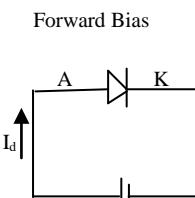


Figure3

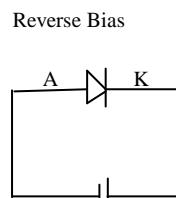


Figure4

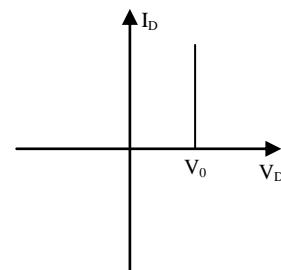


Figure5

In Figure 3, when the voltage across the diode ($V_A - V_K$) is greater than V_0 , called the threshold voltage and defined as the voltage at which the diode begins to conduct, the diode allows a relatively significant forward current I_d to pass; it is said to be forward biased or "conducting".

On the other hand, in Figure 4, when the diode is reverse biased, only a very small (often negligible) current flows, as long as the reverse voltage does not exceed the Zener voltage V_Z ; in this case, the diode is said to be blocked.

An ideal diode would have the characteristic shown in Figure 5:

When the voltage across it is greater than or equal to V_0 , it behaves like a "short circuit".

In the opposite case, it behaves like an "open circuit".

V_0 strongly depends on temperature.

I.1 Dynamic Resistance :

It is possible to show that for small variations near the chosen operating point, the curve $I_D = f(V_D)$ can be approximated as a straight line with the equation: $v_D = V_0 + \rho I_D$.

The parameter ρ is defined as: $\rho = \left(\frac{\Delta v_D}{\Delta I_D} \right) \rightarrow I_D = I_0$ and is called the dynamic resistance. It is clear that ρ varies with the operating point.

I.2 Diode Protection:

Let's consider the half-wave rectifier circuit shown in Figure 6a. If the load R_L is accidentally short-circuited, this can lead to the destruction of the diode.

To prevent this, a protection resistor R_P is added before the diode, as shown in Figure 6b. This resistor limits the current through the diode to a value $I_D \leq I_{Dmax}$, as specified by the manufacturer.

$$e_{max} = v_D + R_P I_{Dmax}, \quad \text{where} \quad R_P \geq \frac{e_{max} - v_D}{I_{Dmax}}$$

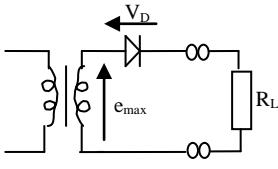


Figure6a

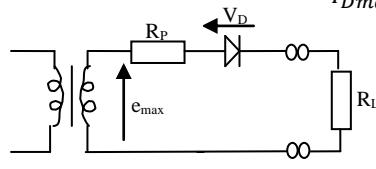


Figure6b

II- Half-Wave Rectification:

Consider the circuit in Figure 7, where $e(t)$ is an AC voltage source, generally obtained from the mains (220V, 50Hz) using a transformer.

Since the diode conducts only when the anode potential V_A is higher than the cathode potential V_K , it can be shown that the voltage V_L across the load R_L will have the following waveform.:

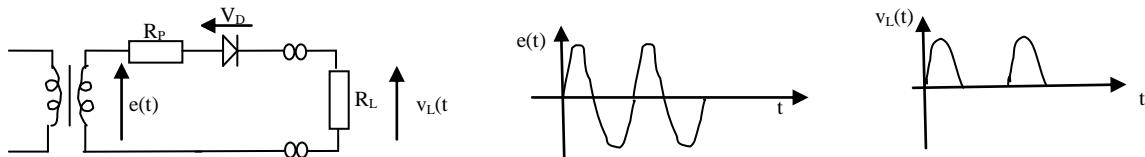


Figure7

Calculation of the Average Voltage Across (R_L):

When the diode is conducting, we can write:

$$e(t) = v_D + (R_P + R_L)i_D$$

with $e(t) = E_m \sin wt$ and $v_D = V_0 + \rho i_D$ we conclude $i_D = \frac{e(t) - v_D}{R_P + R_L + \rho}$

If we consider $E_m \gg V_0$, we can assume that the diode conducts during one half-cycle of the alternating voltage.

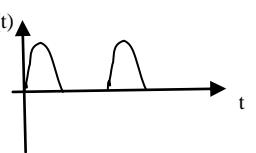
The average voltage across R_L will be: $V_{Lmoy} = \frac{1}{T} \int_0^T v_L(t) dt = R_L \frac{1}{T} \int_0^T i_D(t) dt$

By neglecting R_P and ρ compared to R_L , we obtain:

$$v_L(t) = E_m \sin wt \quad \text{for } 0 < t < \frac{T}{2} \quad \text{and} \quad v_L(t) = 0 \quad \text{for } \frac{T}{2} < t < T$$

$$\text{Finally, } V_{Lmoy} = \frac{1}{T} \int_0^{T/2} E_m \sin wt dt = \frac{E_m}{\pi} \quad \text{and} \quad I_{Dmoy} = \frac{E_m}{\pi R_L}$$

Remark: This result is valid only if $E_m \gg V_0$, $R_L \gg R_P$ and $R_L \gg \rho$.



III- Half-Wave Rectification with Capacitive Filtering:

To achieve a better approximation of a DC voltage, a capacitor is introduced in parallel with R_L (Figure 8).

As a result, the voltage $V_L(t)$ takes the following waveform:

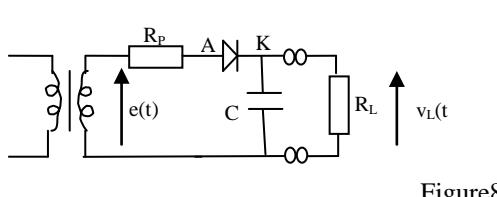
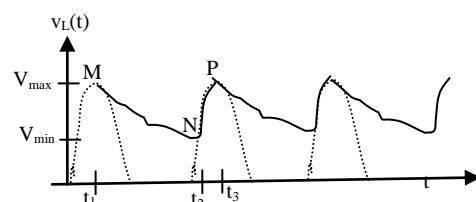


Figure8



Between the instants $t=0$ and $t=t_1=T/4$ (point M),

The **diode is conducting**, and the capacitor charges up to the voltage: $V_{max} \approx E_m$.

Between the instants t_1 (point M) and t_2 (point N), the **diode remains blocked** because the potential of its anode V_A is lower than that of its cathode V_K (which is equal to the voltage of the charged capacitor).

At this stage, the capacitor **discharges** through the resistor R_L down to a value V_{\min} with a time constant: $\tau = R_L C$.

From the instant t_2 (**point N**), the **diode starts conducting again**, allowing the capacitor to **recharge** until the instant $t_3 = 3T/4$ (**point P**).

This **cycle repeats continuously**.

Let $2\Delta v = V_{\max} - V_{\min}$.

It follows that the **charge received** by the capacitor C between t_2 and t_3 is:

$$Q_{\text{received}} = C(2\Delta v)$$

When the capacitor **discharges** through R_L from **M** to **N**, the **charge lost** is:

$$Q_{\text{lost}} = i_{\text{avg}}(t_2 - t_1)$$

$$\text{With } i_{\text{moy}} = v_{\text{moy}}/R_L$$

Since we can approximate $t_2 \approx T$ and $t_1 \ll T$ (which is valid when $\tau \gg T$), we get: $Q_{\text{lost}} = i_{\text{avg}}T$

By charge conservation, we equate $Q_{\text{received}} = Q_{\text{lost}}$, leading to:

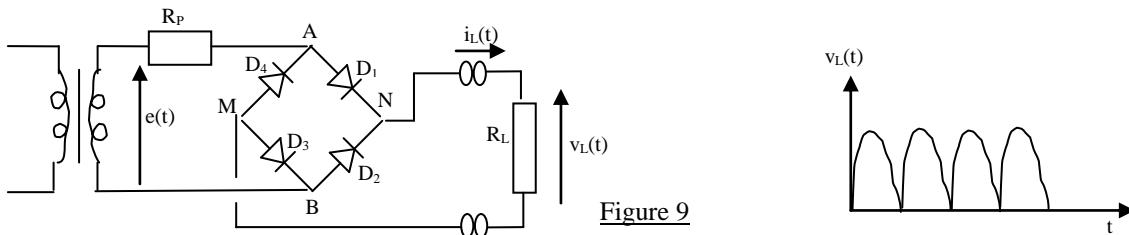
Since for **mains rectification**, the frequency is **f=50Hz** and **T=1/f**, we can rewrite:

$$\frac{\Delta v}{v_{\text{avg}}} = \frac{T}{2R_L C} = \frac{1}{2R_L C f}$$

This result is only valid if $\tau = R_L C \gg T$.

IV- Full-Wave Rectification:

Let's consider the circuit diagram in Figure 9:



For $0 < t < T/2$, during the **positive half-cycle** of $e(t)$:

- The potential at **point A** is higher, and the potential at **point B** is lower.
- **Diodes D_1 and D_3 conduct**, while **D_2 and D_4 are blocked**.

For $T/2 < t < T$, during the **negative half-cycle** of $e(t)$:

- The potential at **point A** is lower, and the potential at **point B** is higher.
- **Diodes D_1 and D_3 are blocked**, while **D_2 and D_4 conduct**.

As a result, the current $i_L(t)$ always flows in the same direction. The output voltage $T/2 < t < T$ $v_L(t)$ remains **always positive**, but with a period reduced by half, meaning the frequency is **doubled**: $f=100\text{Hz}$.

By applying the same assumptions as for **half-wave rectification**, it is easy to show that the **average voltage** will be: $V_{L\text{avg}} = 2 \frac{E_m}{\pi}$.

V- Full-Wave Rectification with Capacitive Filtering:

As with half-wave rectification, it is sufficient to add a capacitor C in parallel with the load resistor R_L .

The same reasoning applies, but with $f=100\text{Hz}$ and $T'=T/2$.

We find,

$$\frac{\Delta v}{v_{\text{avg}}} = \frac{T'}{2R_L C} = \frac{1}{2R_L C f'}$$

VI-Stabilization:

VI.1 The Zener Diode:

The reverse current-voltage characteristic of a Zener diode is shown in the figure 10:

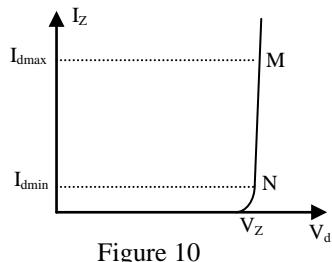


Figure 10

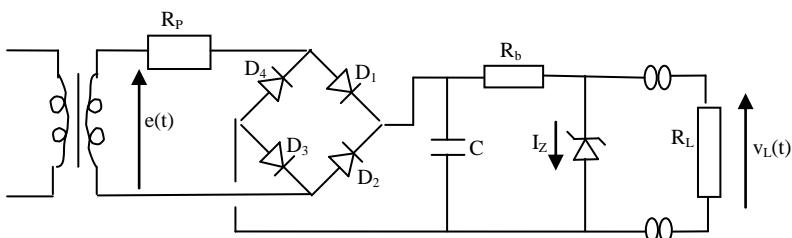


Figure 11

When the voltage across the **Zener diode** reaches V_Z , the current increases sharply, whereas it was almost zero for $V_d < V_Z$.

As a result, the **dynamic resistance** of the diode is **very low** for $V_d > V_Z$. This property is used for **voltage stabilization**.

The **operating point** of the diode is always chosen in the **linear region MN**.

VI.2 Voltage Regulator Circuit:

The goal is to obtain a stable output voltage regardless of variations in the input voltage and load variations.

One solution is to use the voltage regulator circuit shown in Figure 11.

The output voltage $v_L(t)$ will be regulated only if the Zener current I_Z remains within the linear region MN of its characteristic curve.

This condition imposes limits on the variations of R_L and $e(t)$.

The circuit elements are calculated such that a sufficient current I_Z flows through the Zener diode, ensuring a voltage close to V_Z across the load.